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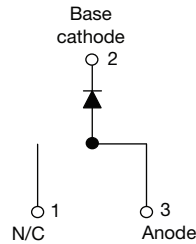
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



## High Performance Schottky Rectifier, 8 A


**D²PAK**


### FEATURES

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### PRODUCT SUMMARY

|                                  |                  |
|----------------------------------|------------------|
| I <sub>F(AV)</sub>               | 8 A              |
| V <sub>R</sub>                   | 80 V, 100 V      |
| V <sub>F</sub> at I <sub>F</sub> | 0.58 V           |
| I <sub>RM</sub>                  | 7 mA at 125 °C   |
| T <sub>J</sub> max.              | 175 °C           |
| E <sub>AS</sub>                  | 7.5 mJ           |
| Package                          | TO-263AB (D²PAK) |
| Diode variation                  | Single die       |

### DESCRIPTION

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### MAJOR RATINGS AND CHARACTERISTICS

| SYMBOL             | CHARACTERISTICS                             | VALUES     | UNITS |
|--------------------|---|------------|-------|
| I <sub>F(AV)</sub> | Rectangular waveform                        | 8          | A     |
| V <sub>RRM</sub>   | Range                                       | 80/100     | V     |
| I <sub>FSM</sub>   | t <sub>p</sub> = 5 μs sine                  | 850        | A     |
| V <sub>F</sub>     | 8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.58       | V     |
| T <sub>J</sub>     | Range                                       | -55 to 175 | °C    |

### VOLTAGE RATINGS

| PARAMETER                            | SYMBOL           | VS-8TQ080SHM3 | VS-8TQ100SHM3 | UNITS |
|--------------------------------------|------------------|---------------|---------------|-------|
| Maximum DC reverse voltage           | V <sub>R</sub>   | 80            | 100           | V     |
| Maximum working peak reverse voltage | V <sub>RWM</sub> |               |               |       |

### ABSOLUTE MAXIMUM RATINGS

| PARAMETER  | SYMBOL             | TEST CONDITIONS  | VALUES | UNITS |
|--|--------------------|--|--------|-------|
| Maximum average forward current<br>See fig. 5                        | I <sub>F(AV)</sub> | 50 % duty cycle at T <sub>C</sub> = 157 °C, rectangular waveform   | 8      | A     |
| Maximum peak one cycle<br>non-repetitive surge current<br>See fig. 7 | I <sub>FSM</sub>   | 5 μs sine or 3 μs rect. pulse  | 850    | A     |
|  |                    | 10 ms sine or 6 ms rect. pulse   | 230    |       |
| Non-repetitive avalanche energy                                      | E <sub>AS</sub>    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH  | 7.50   | mJ    |
| Repetitive avalanche current   | I <sub>AR</sub>    | Current decaying linearly to zero in 1 μs<br>Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical | 0.50   | A     |



| ELECTRICAL SPECIFICATIONS                     |                |   |                                   |        |                  |
|---|----------------|---|-----------------------------------|--------|------------------|
| PARAMETER                                     | SYMBOL         | TEST CONDITIONS   |                                   | VALUES | UNITS            |
| Maximum forward voltage drop<br>See fig. 1    | $V_{FM}^{(1)}$ | 8 A   | $T_J = 25\text{ }^\circ\text{C}$  | 0.72   | V                |
|   |                | 16 A  |                                   | 0.88   |                  |
|   |                | 8 A   | $T_J = 125\text{ }^\circ\text{C}$ | 0.58   |                  |
|   |                | 16 A  |                                   | 0.69   |                  |
| Maximum reverse leakage current<br>See fig. 2 | $I_{RM}^{(1)}$ | $T_J = 25\text{ }^\circ\text{C}$  | $V_R = \text{Rated } V_R$         | 0.55   | mA               |
|   |                | $T_J = 125\text{ }^\circ\text{C}$   |                                   | 7      |                  |
| Maximum junction capacitance                  | $C_T$          | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$ |                                   | 500    | pF               |
| Typical series inductance                     | $L_S$          | Measured lead to lead 5 mm from package body                                      |                                   | 8      | nH               |
| Maximum voltage rate of change                | dV/dt          | Rated $V_R$   |                                   | 10 000 | V/ $\mu\text{s}$ |

Note

(1) Pulse width < 300  $\mu\text{s}$ , duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS            |                |                                      |  |            |                           |
|--|----------------|--------------------------------------|--|------------|---------------------------|
| PARAMETER                                      | SYMBOL         | TEST CONDITIONS                      |  | VALUES     | UNITS                     |
| Maximum junction and storage temperature range | $T_J, T_{Stg}$ |                                      |  | -55 to 175 | $^\circ\text{C}$          |
| Maximum thermal resistance, junction to case   | $R_{thJC}$     | DC operation<br>See fig. 4           |  | 2.0        | $^\circ\text{C}/\text{W}$ |
| Typical thermal resistance, case to heatsink   | $R_{thCS}$     | Mounting surface, smooth and greased |  | 0.50       |                           |
| Approximate weight                             |                |                                      |  | 2          | g                         |
|  |                |                                      |  | 0.07       | oz.                       |
| Mounting torque                                | minimum        |                                      |  | 6 (5)      | kgf · cm<br>(lbf · in)    |
|  | maximum        |                                      |  | 12 (10)    |                           |
| Marking device                                 |                | Case style D <sup>2</sup> PAK        |  | 8TQ080SH   |                           |
|  |                |                                      |  | 8TQ100SH   |                           |



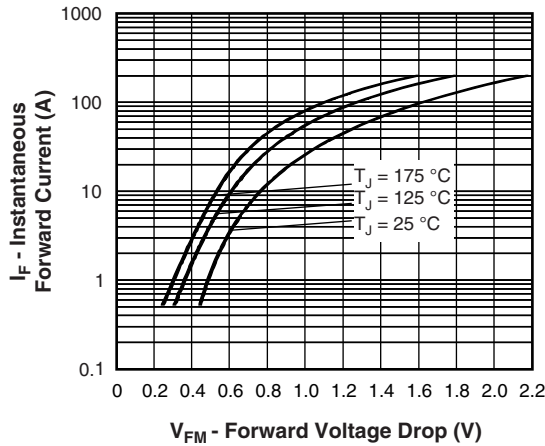


Fig. 1 - Maximum Forward Voltage Drop Characteristics

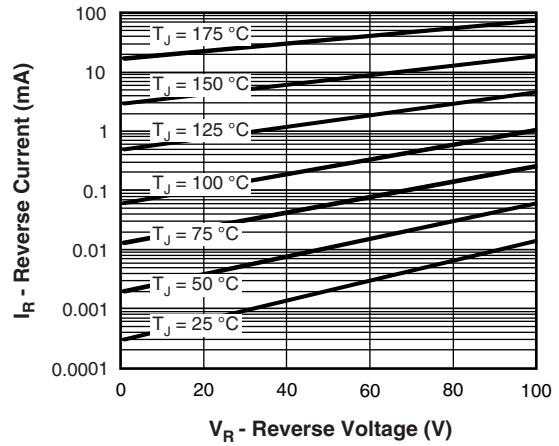


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

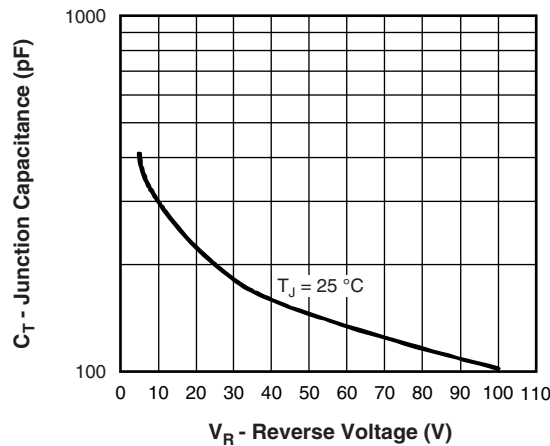


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

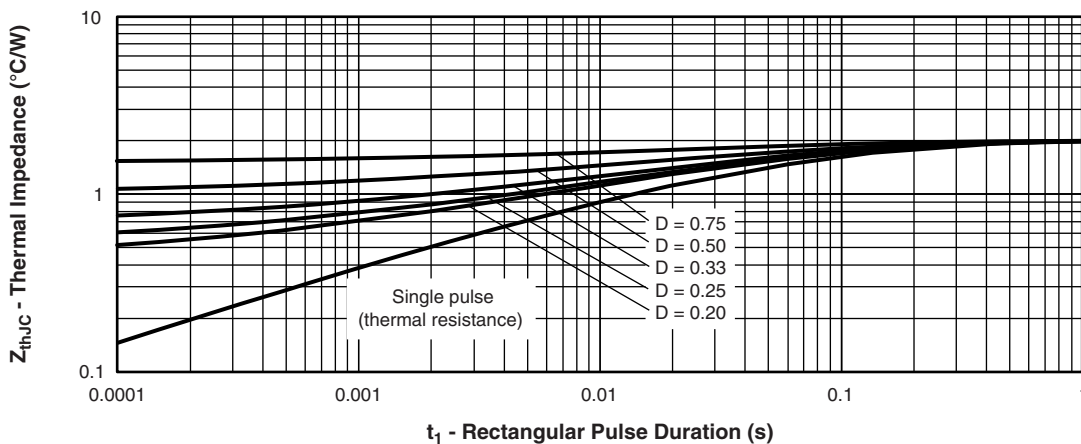


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

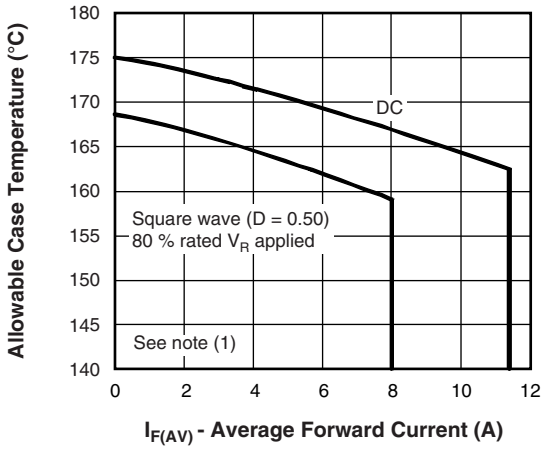


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

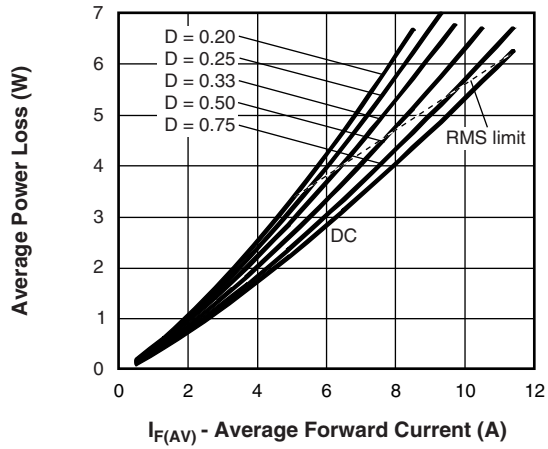


Fig. 6 - Forward Power Loss Characteristics

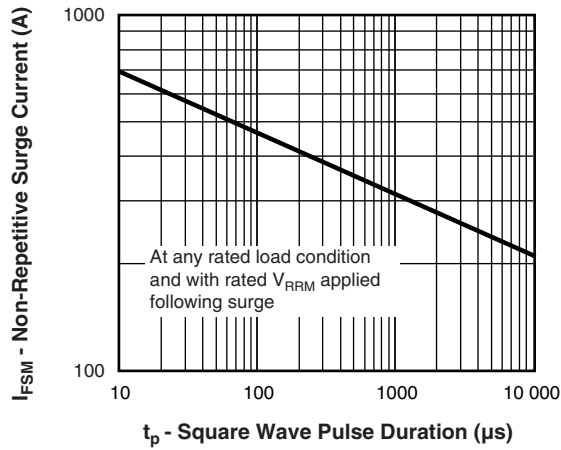


Fig. 7 - Maximum Non-Repetitive Surge Current

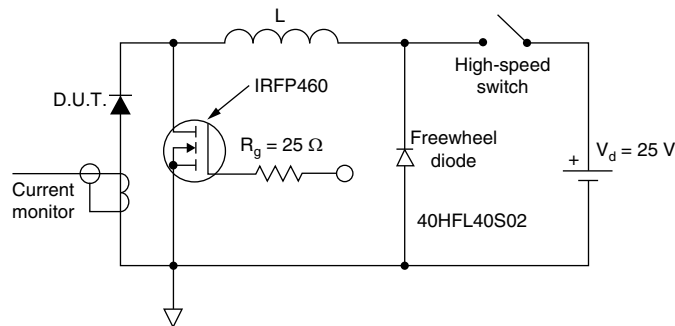


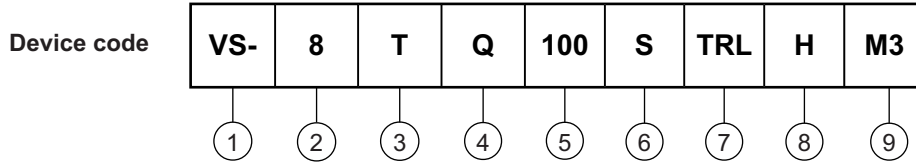
Fig. 8 - Unclamped Inductive Test Circuit

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{dREV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$



## ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (8 A)
- 3** - Circuit configuration: T = TO-220
- 4** - Schottky "Q" series
- 5** - Voltage ratings 080 = 80 V  
100 = 100 V
- 6** - S = D<sup>2</sup>PAK
- 7** -
  - None = Tube
  - TRL = Tape and reel (left oriented)
  - TRR = Tape and reel (right oriented)
- 8** - H = AEC-Q101 qualified
- 9** - M3 = Halogen-free, RoHS-compliant and termination lead (Pb)-free

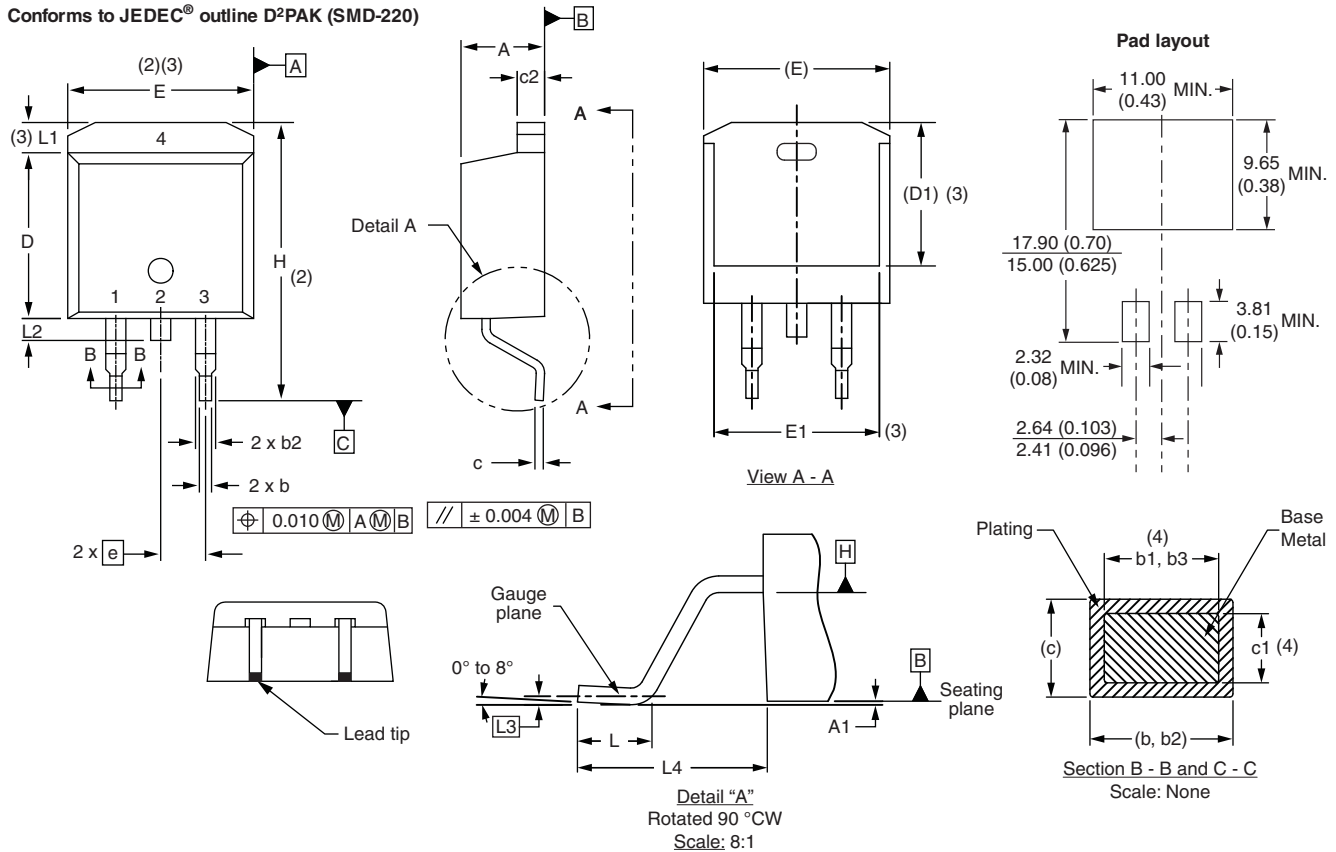
| ORDERING INFORMATION |                  |                        |                          |
|----------------------|------------------|------------------------|--------------------------|
| PREFERRED P/N        | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION    |
| VS-8TQ080SHM3        | 50               | 1000                   | Antistatic plastic tubes |
| VS-8TQ080STRRHM3     | 800              | 800                    | 13" diameter reel        |
| VS-8TQ080STRLHM3     | 800              | 800                    | 13" diameter reel        |
| VS-8TQ100SHM3        | 50               | 1000                   | Antistatic plastic tubes |
| VS-8TQ100STRRHM3     | 800              | 800                    | 13" diameter reel        |
| VS-8TQ100STRLHM3     | 800              | 800                    | 13" diameter reel        |

| LINKS TO RELATED DOCUMENTS |  |
|----------------------------|--|
| Dimensions                 | <a href="http://www.vishay.com/doc?95046">www.vishay.com/doc?95046</a> |
| Part marking information   | <a href="http://www.vishay.com/doc?95444">www.vishay.com/doc?95444</a> |
| Packaging information      | <a href="http://www.vishay.com/doc?95032">www.vishay.com/doc?95032</a> |
| SPIICE model               | <a href="http://www.vishay.com/doc?95291">www.vishay.com/doc?95291</a> |

## D<sup>2</sup>PAK

### DIMENSIONS in millimeters and inches

Conforms to JEDEC® outline D<sup>2</sup>PAK (SMD-220)



| SYMBOL | MILLIMETERS |       | INCHES |       | NOTES | SYMBOL | MILLIMETERS |       | INCHES    |       | NOTES |
|--------|-------------|-------|--------|-------|-------|--------|-------------|-------|-----------|-------|-------|
|        | MIN.        | MAX.  | MIN.   | MAX.  |       |        | MIN.        | MAX.  | MIN.      | MAX.  |       |
| A      | 4.06        | 4.83  | 0.160  | 0.190 |       | D1     | 6.86        | 8.00  | 0.270     | 0.315 | 3     |
| A1     | 0.00        | 0.254 | 0.000  | 0.010 |       | E      | 9.65        | 10.67 | 0.380     | 0.420 | 2, 3  |
| b      | 0.51        | 0.99  | 0.020  | 0.039 |       | E1     | 7.90        | 8.80  | 0.311     | 0.346 | 3     |
| b1     | 0.51        | 0.89  | 0.020  | 0.035 | 4     | e      | 2.54 BSC    |       | 0.100 BSC |       |       |
| b2     | 1.14        | 1.78  | 0.045  | 0.070 |       | H      | 14.61       | 15.88 | 0.575     | 0.625 |       |
| b3     | 1.14        | 1.73  | 0.045  | 0.068 | 4     | L      | 1.78        | 2.79  | 0.070     | 0.110 |       |
| c      | 0.38        | 0.74  | 0.015  | 0.029 |       | L1     | -           | 1.65  | -         | 0.066 | 3     |
| c1     | 0.38        | 0.58  | 0.015  | 0.023 | 4     | L2     | 1.27        | 1.78  | 0.050     | 0.070 |       |
| c2     | 1.14        | 1.65  | 0.045  | 0.065 |       | L3     | 0.25 BSC    |       | 0.010 BSC |       |       |
| D      | 8.51        | 9.65  | 0.335  | 0.380 | 2     | L4     | 4.78        | 5.28  | 0.188     | 0.208 |       |

#### Notes

- Dimensioning and tolerancing per ASME Y14.5 M-1994
- Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- Thermal pad contour optional within dimension E, L1, D1 and E1
- Dimension b1 and c1 apply to base metal only
- Datum A and B to be determined at datum plane H
- Controlling dimension: inch
- Outline conforms to JEDEC® outline TO-263AB



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